NSN 5961-00-173-4885

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-173-4885 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage/static/base open and 50.0 collector to emitter voltage, dc with specified circuit between base and emitter and 50.0 collector to base voltage, dc and 5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** Between 7.50 amperes source cutoff current and 30.00 amperes collector current, dc **Power Rating Per Characteristic:** 200.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: